TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT process)

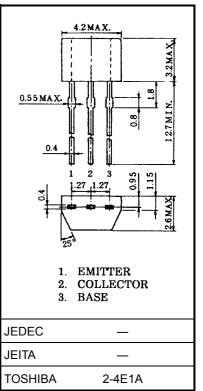
2SC2459

Audio Amplifier Applications

- High breakdown voltage: $V_{CEO} = 120 V (max)$
- High DC current gain: $h_{FE} = 200 \sim 700$
- Excellent hFE linearity: hFE (IC = 0.1 mA)/hFE (IC = 2 mA) = 0.95 (typ.)
- Low noise: NF = 1dB (typ.), 10dB (max)
- Complementary to 2SA1049.
- Small package.

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V _{CBO}	120	V
Collector-emitter voltage	V _{CEO}	120	V
Emitter-base voltage	V _{EBO}	5	V
Collector current	Ι _C	100	mA
Base current	Ι _Β	20	mA
Collector power dissipation	P _C	200	mW
Junction temperature	Tj	125	°C
Storage temperature range	T _{stg}	-55~125	°C



Weight: 0.13 g (typ.)

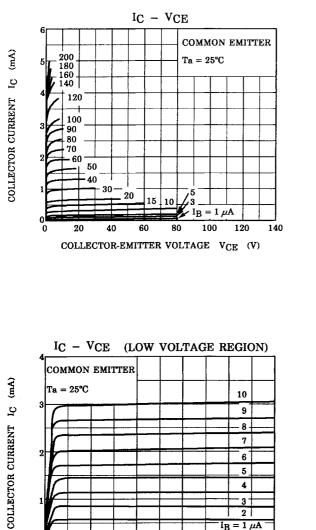
Electrical Characteristics (Ta = 25°C)

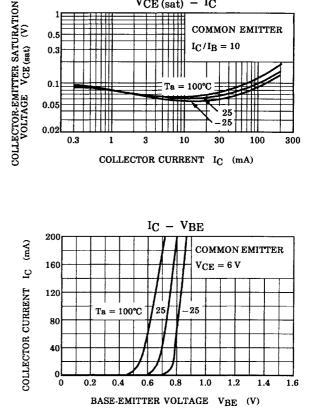
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	$V_{CB} = 120 \text{ V}, \text{ I}_{E} = 0$			0.1	μA
Emitter cut-off current	I _{EBO}	$V_{EB} = 5 V, I_C = 0$	_	_	0.1	μA
DC current gain	h _{FE} (Note)	$V_{CE} = 6 \text{ V}, \text{ I}_{C} = 2 \text{ mA}$	200	_	700	
Collector-emitter saturation voltage	V _{CE (sat)}	$I_{C} = 10 \text{ mA}, I_{B} = 1 \text{ mA}$	_		0.3	V
Transition frequency	f _T	$V_{CE} = 6 V, I_{C} = 1 mA$	_	100		MHz
Collector output capacitance	C _{ob}	$V_{CB} = 10 \text{ V}, \text{ I}_{E} = 0, \text{ f} = 1 \text{ MHz}$	_	3.0		pF
Noise figure	NF	$V_{CE} = 6 \text{ V}, \text{ I}_{C} = 0.1 \text{ mA},$ f = 1 kHz, R _G = 10 k Ω		1.0	10	dB

Note: hFE classification GR: 200~400, BL: 350~700

Unit: mm

TOSHIBA





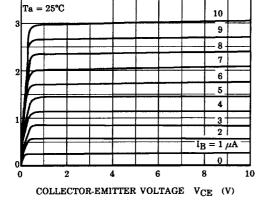
VCE (sat) - IC

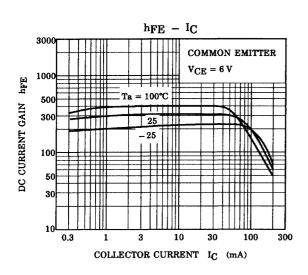
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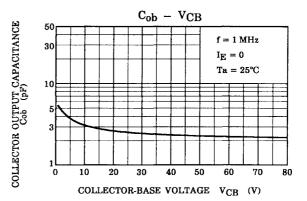
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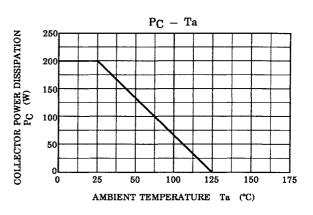
COMMON EMITTER

 $I_{\rm C}/I_{\rm B}=10$









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